**Preferred Device** 

**Amplifier Transistor** 

# **PNP Silicon**

#### Features

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	50	mAdc
Total Device Dissipation @ $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation @ $T_C = 25^{\circ}C$ Derate above $25^{\circ}C$	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

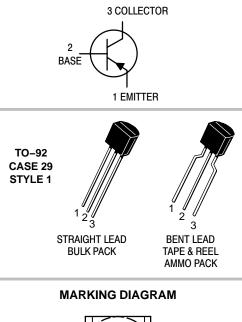
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

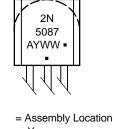
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



# **ON Semiconductor®**

http://onsemi.com





А Υ = Year WW = Work Week

= Pb-Free Package (Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
2N5087	TO-92	5000 Units / Bulk
2N5087G	TO–92 (Pb–Free)	5000 Units / Bulk
2N5087RLRAG	TO–92 (Pb–Free)	2000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use

and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

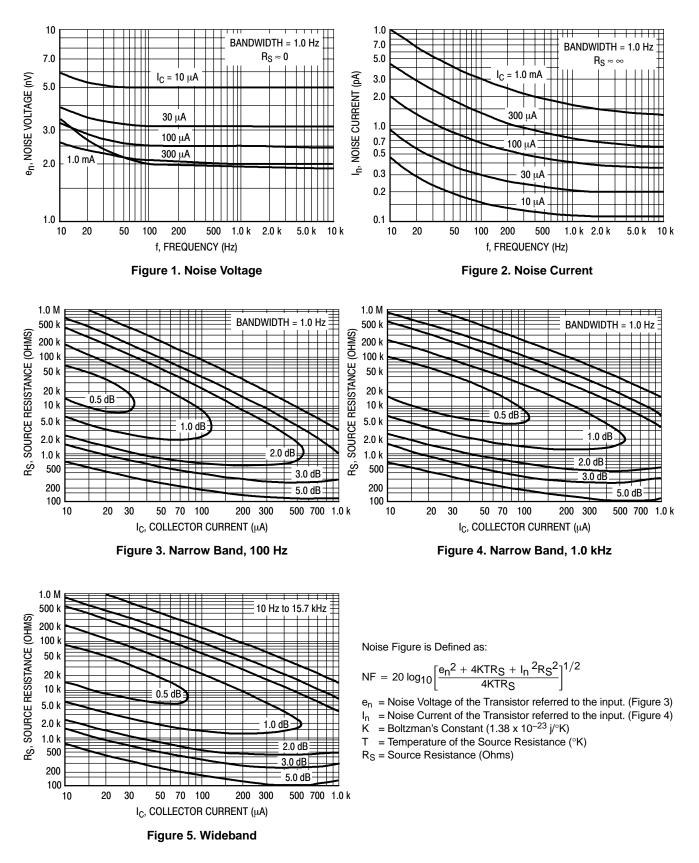
Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					•
Collector-Emitter Breakdown Voltage	(Note 1) $(I_{C} = 1.0 \text{ mAdc}, I_{B} = 0)$	V <sub>(BR)CEO</sub>	50	-	Vdc
Collector-Base Breakdown Voltage	$(I_{C} = 100 \ \mu Adc, I_{E} = 0)$	V <sub>(BR)CBO</sub>	50	_	Vdc
Collector Cutoff Current	$(V_{CB} = 35 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	_	50	nAdc
Emitter Cutoff Current	$(V_{EB} = 3.0 \text{ Vdc}, I_{C} = 0)$	I <sub>EBO</sub>	_	50	nAdc
ON CHARACTERISTICS					
DC Current Gain		h <sub>FE</sub>	250 250 250	800 - -	_
Collector-Emitter Saturation Voltage	(I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc)	V <sub>CE(sat)</sub>	_	0.3	Vdc
Base-Emitter On Voltage	(I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 5.0 Vdc)	$V_{\text{BE(on)}}$	-	0.85	Vdc
SMALL-SIGNAL CHARACTERISTIC	S		•	•	•
Current-Gain - Bandwidth Product	$(I_{C} = 500 \ \mu Adc, \ V_{CE} = 5.0 \ Vdc, \ f = 20 \ MHz)$	f <sub>T</sub>	40	_	MHz
Collector-Base Capacitance		C <sub>cb</sub>			pF

Collector–Base Capacitance	C <sub>cb</sub>			pF
$(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MH}$	z)	-	4.0	P.
Small–Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 5.0 Vdc, f = 1.0 kH	h <sub>fe</sub>	250	900	-
Noise Figure	NF			dB
$(I_{C} = 20 \ \mu Adc, V_{CE} = 5.0 \ Vdc, R_{S} = 1.0 \ k\Omega, f = 1.0 \ kH$ $(I_{C} = 100 \ \mu Adc, V_{CE} = 5.0 \ Vdc, R_{S} = 3.0 \ k\Omega, f = 1.0 \ kH$			2.0 2.0	

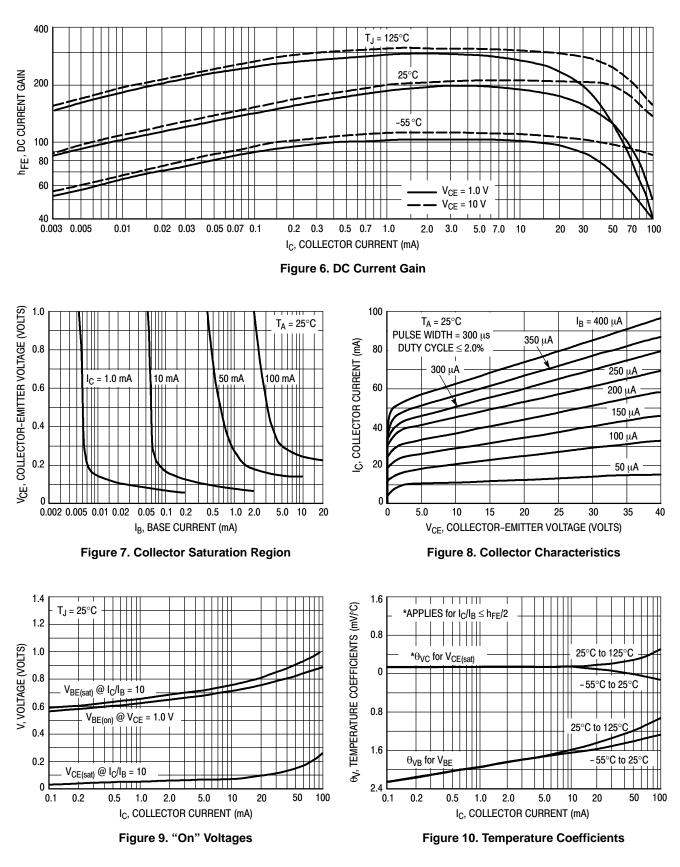
1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

#### **TYPICAL NOISE CHARACTERISTICS**

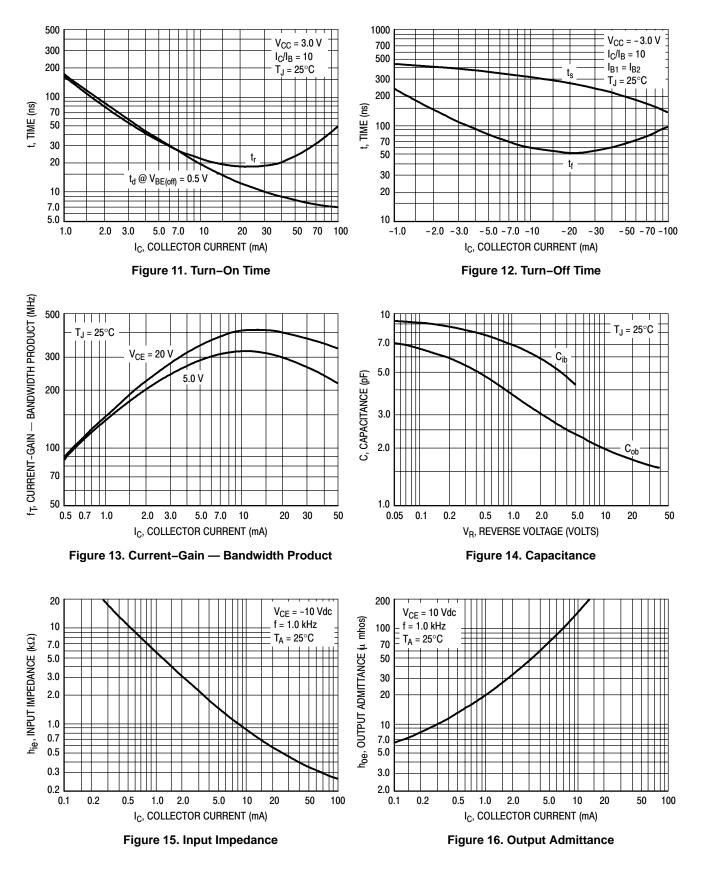
 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}C)$ 







## **TYPICAL DYNAMIC CHARACTERISTICS**



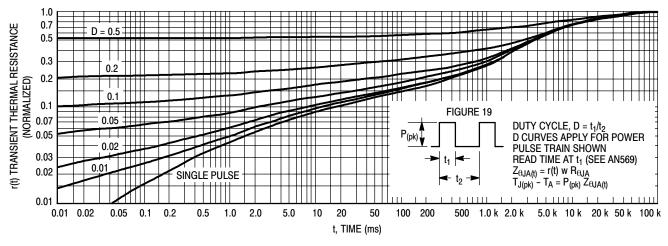


Figure 17. Thermal Response

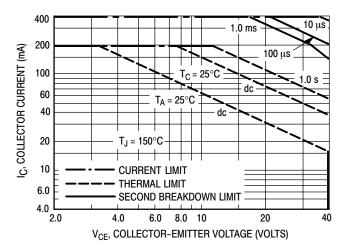


Figure 18. Active–Region Safe Operating Area

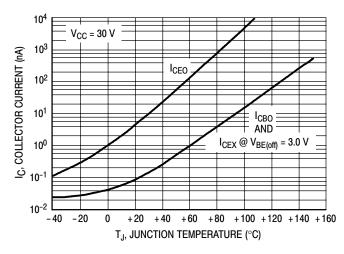


Figure 19. Typical Collector Leakage Current

The safe operating area curves indicate  $I_C-V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 18 is based upon  $T_{J(pk)} = 150^{\circ}$ C;  $T_{C}$  or  $T_{A}$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150^{\circ}$ C.  $T_{J(pk)}$  may be calculated from the data in Figure 17. At high case or ambient temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

#### DESIGN NOTE: USE OF THERMAL RESPONSE DATA

A train of periodical power pulses can be represented by the model as shown in Figure 19. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 17 was calculated for various duty cycles.

To find  $Z_{\theta JA(t)}$ , multiply the value obtained from Figure 17 by the steady state value  $R_{\theta JA}$ .

Example:

The 2N5087 is dissipating 2.0 watts peak under the following conditions:

$$t_1 = 1.0 \text{ ms}, t_2 = 5.0 \text{ ms} (D = 0.2)$$

Using Figure 17 at a pulse width of 1.0 ms and D = 0.2, the reading of r(t) is 0.22.

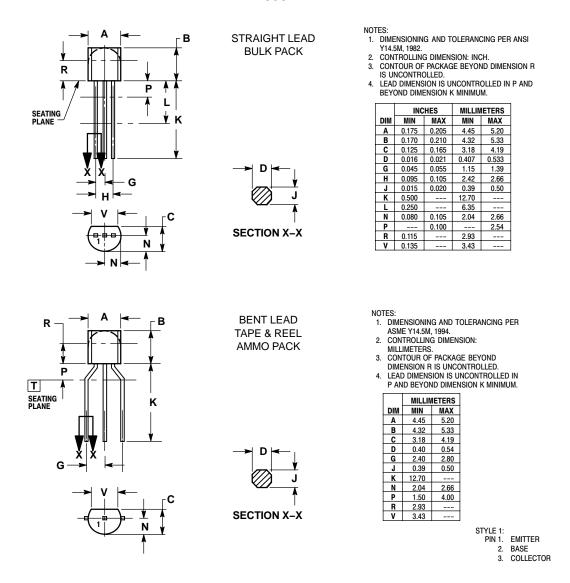
The peak rise in junction temperature is therefore

 $\Delta T = r(t) \ge P_{(pk)} \ge R_{\theta JA} = 0.22 \ge 2.0 \ge 200 = 88^{\circ}C.$ 

For more information, see ON Semiconductor Application Note AN569/D, available from the Literature Distribution Center or on our website at **www.onsemi.com**.

#### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM** 



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